

# Poster Presentations

## Photonics and Optoelectronics:

1. Ch. Deutsch, A. Benz, G. Fasching, K. Unterrainer, A. M. Andrews, P. Klang, W. Schrenk, G. Strasser, *Performance of Phonon Depopulated Terahertz Quantum Cascade Lasers* – **page 65**
2. A. Benz, Ch. Deutsch, G. Fasching, K. Unterrainer, A.M. Andrews, P. Klang, W. Schrenk, G. Strasser, *Photonic Crystal Frequency Control in Terahertz Lasers* – **page 69**
3. G. Chen, V. Lavchiev, F. Schäffler, G. Bauer, W. Jantsch, *Fabrication of Ordered Ge Quantum Island Arrays on Prepatterned SOI Platform for Waveguide Photodetectors and Emitters* – **page 73**
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